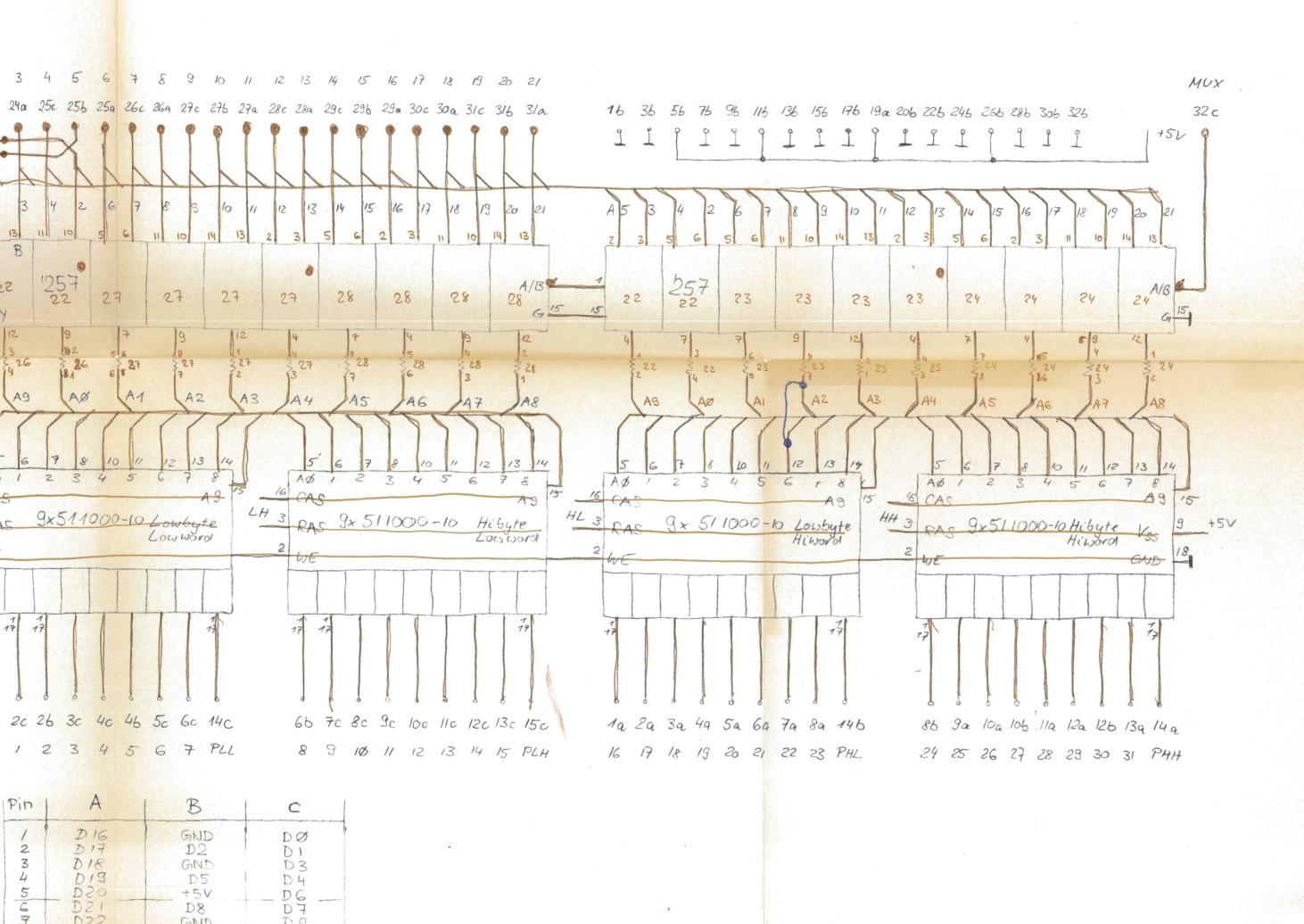
A 2 3 4 5 6 7 8 9 10 11 12 13 14 15 16 17 18 19 20 21 190 \* 3× 2CASB 220-24c 24a 25c 25b 25g 26c 26g 27c 27b 27a 28c 28a 29c 29b 29a 30c 30a 31c 31b 3/a 16 36 56 75 96 115 136 156 74F10 2CASA 216 \* 025 CASLL 200 LHCAS 13 3 3 5 2 14 13 CASLH 2100 HLCAS 27 88 22 27 28 23 27 27 28 CASHL 2000 HHCAS CASHH 2120 A6 LLRAS LHRAS Ad 16 LL 9x511000-10 Lowbyte 9 x 5/ 1000-10 Lowby Hiword 3 RAS 9x 511000-10 Hibyte LOWWOOD Lowword 2RAS B 1700 HHRAS 166 \* 2RASA 6 R/W 3200 66 7c 8c 9c 100 110 120 130 150 10 20 26 30 40 46 50 60 14C 1a 2a 3a 49 5a 6a 7a 8a Ø 1 2 3 4 5 6 7 PLL 8 9 10 11 12 13 14 15 PLH 16 17 18 19 20 21 22 23 28ASB 1900 2CASA A 2. 4 MB-Block B Pin C 2 RASB D 16 D 17 GND DØ D2 1660 DI D18 GND D3 DSD 010 D5 D4 3 CASB 22 a 0 \* D6 D7 +5V D8 CAIR

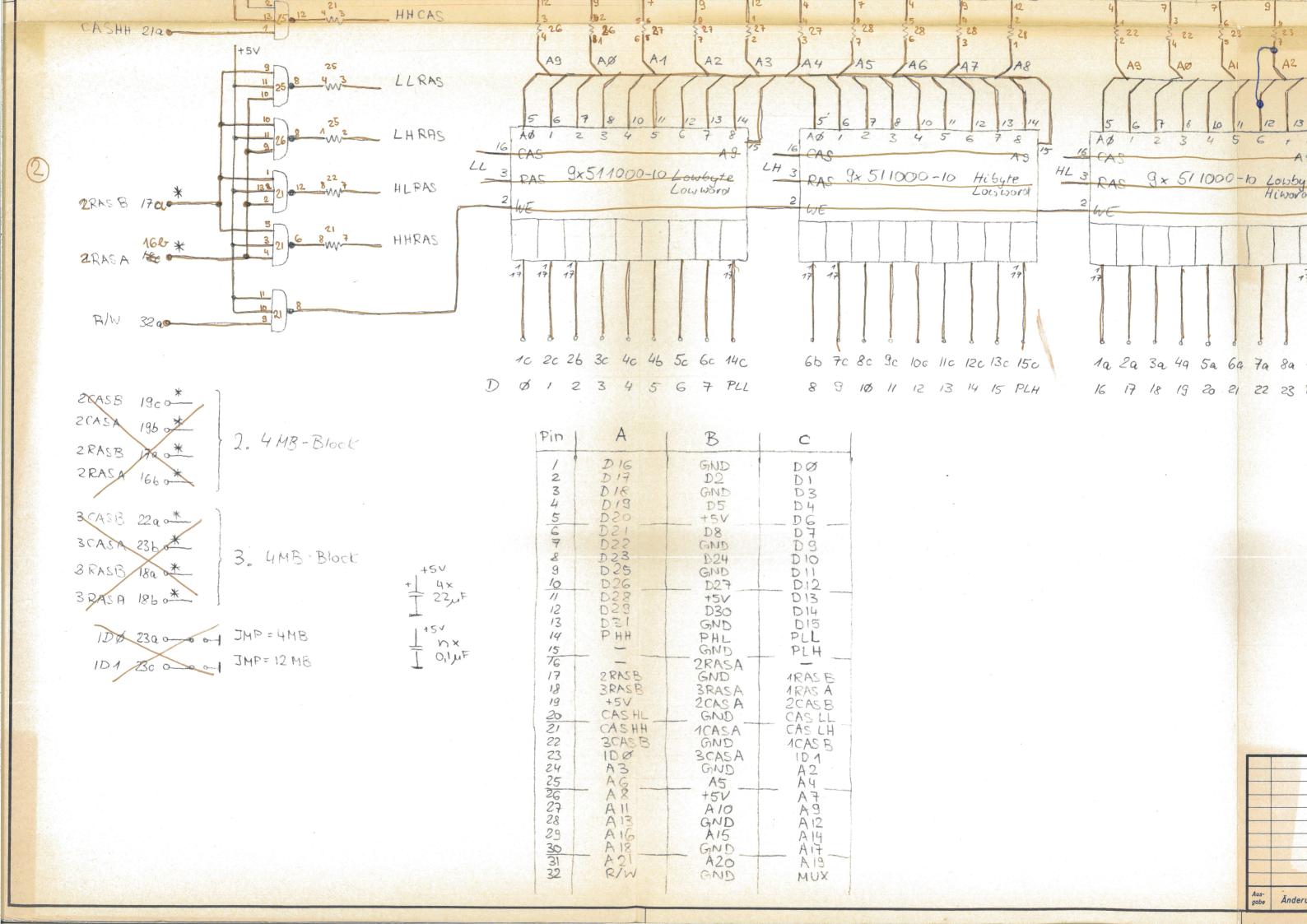


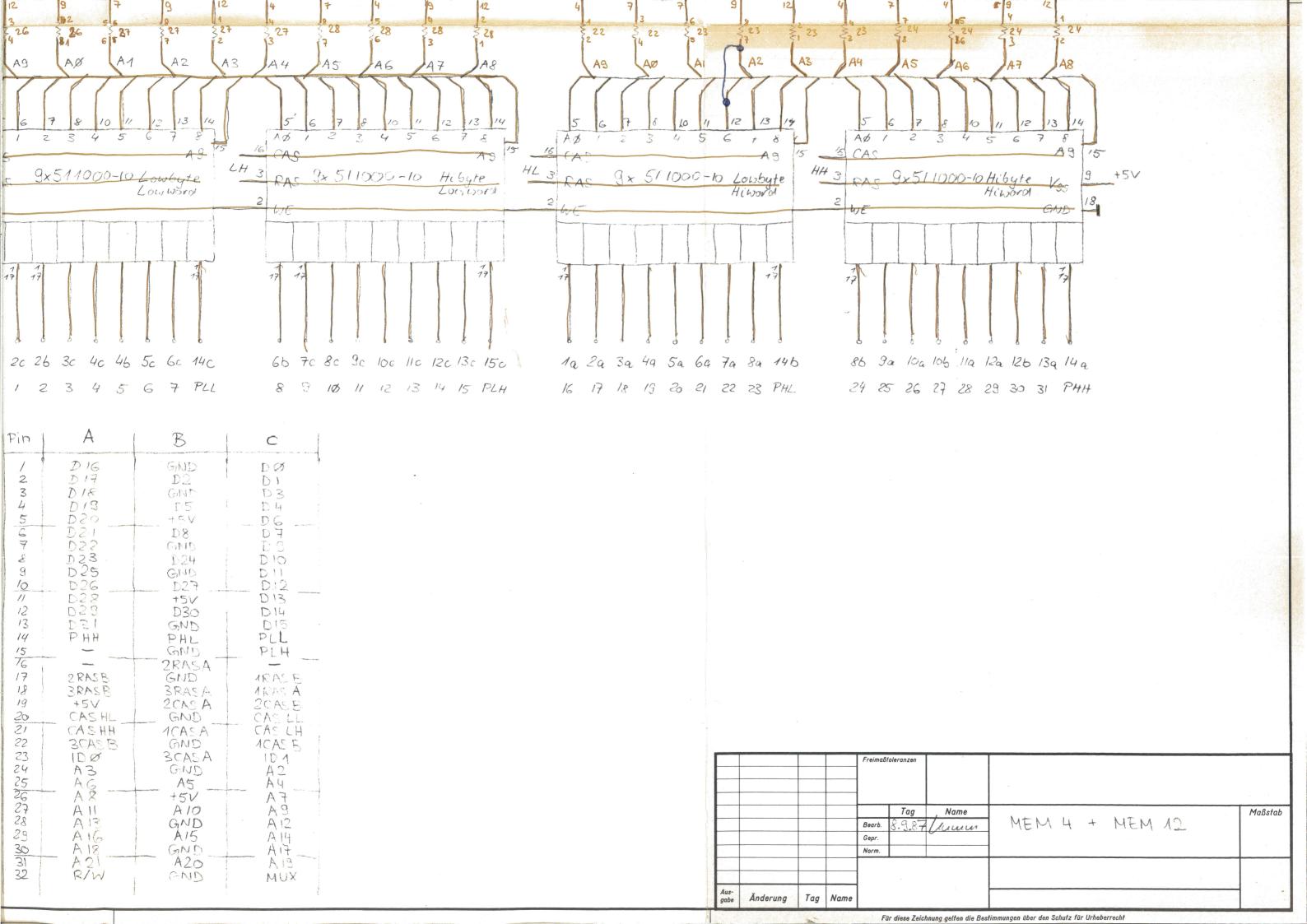
GIND D5

+5V

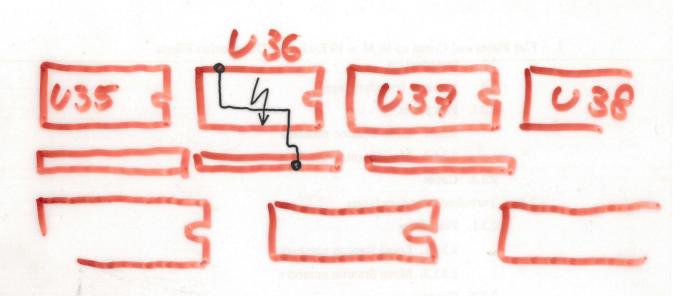
D8 CALL D4

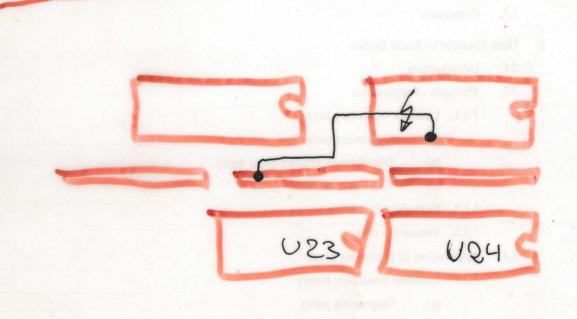
D6 D7





## MEM 4/12 (COMPO)





bei 12 MByte Ger 2 Unterbrechen unter un /C (Absichtliche Murzschlüsse gegen Erweiterung 4 \* 12 durch Nachbestücken)